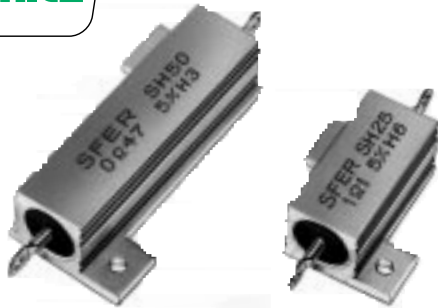




heat sink encased wirewound power resistors – industrial applications

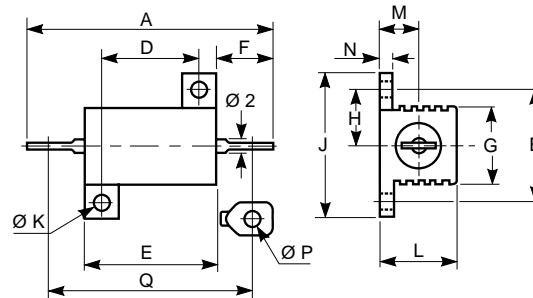


Built for high power dissipation applications, these components have very good overall features for industrial use under harsh environmental conditions. They feature :

- HIGH POWER CHARACTERISTICS
- UTILIZE HEAT SINK CAPABILITY
- GOOD MECHANICAL PROTECTION
- INDUSTRIALIZE PRODUCT

Table 1

Series and styles	SH5	SH10	SH25	SH50
A	28,5 ±1,5	35 ±1,5	49 ±1,3	70,2 ±1,4
B ±0,2	12,5	15,9	19,8	21,4
D ±0,2	11,3	14	18,3	39,7
E ±0,5	16,3	19	28	50
F	6,8 ±1,5	7,9 ±1,5	11,1 ±1,5	11 ±1,2
G ±1	8,5	11	14	15,5
H ±0,7	6,2	7,9	9,9	10,7
J ±0,5	16,4	20,6	27,5	29,4
Ø K ±0,1	2,4	2,4	3,2	3,2
L max.	8,9	11	15	15
M ±0,5	4,3	5,6	8	8
N ±0,3	1,6	2	2,4	2,4
Ø P min.	2,1	2,1	2,1	2,1
Q	25,3 ±1,5	30,6 ±1,5	44,6 ±1,3	66,5 ±1,4
Weight in g	3	8,8	16,5	30,8



Dimensions in mm

Fig. 1

SPECIFICATIONS

Table 2

SFERNICE SERIES AND STYLES		SH5	SH10	SH25	SH50
POWER RATING	Chassis mounted resistors: 413 cm ² for SH5 and SH10 536 cm ² for SH25 and SH50	at 25°C 10 W	12,5 W	25 W	50 W
		at 70°C 8 W	10 W	20 W	40 W
POWER RATING	Unmounted resistors	at 25°C 4 W	6 W	9 W	12 W
		at 70°C 3,2 W	4,8 W	7,2 W	9,6 W
OHMIC VALUES		0,1 Ω 3,3 kΩ	0,1 Ω 15 kΩ	0,1 Ω 33 kΩ	0,1 Ω 51 kΩ
TOLERANCE		± 1% to ± 5%			
RATED MAXIMUM VOLTAGE		160 V	250 V	550 V	1285 V
DIELECTRIC STRENGTH V _{RMS}		800 V	1000 V	2000 V	2000 V
INSULATION RESISTANCE		>10 ⁴ MΩ		>3.10 ⁴ MΩ	
TEMPERATURE COEFFICIENT		± 50 ppm/°C R _n >50 Ω			
CLIMATIC CATEGORY		55 / 200 / 56			
TEMPERATURE LIMITS		-55°C +200°C			

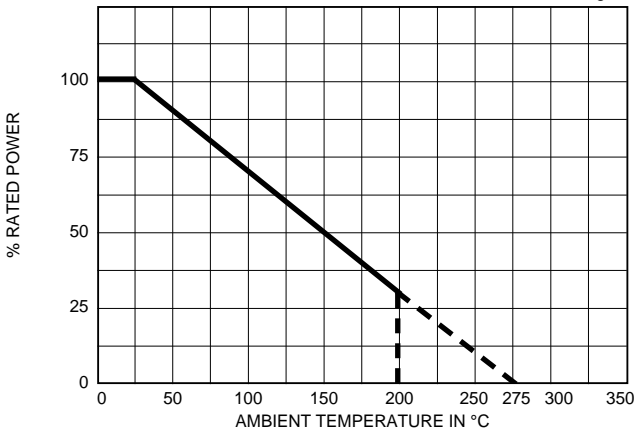
PERFORMANCES

Table 3

TESTS	CONDITIONS	TYPICAL DRIFTS
MOMENTARY OVERLOAD	5 Pn / 5 s	± 0,5% max. + 0,05 Ω
CLIMATIC SEQUENCE	-55°C +200°C 5 cycles	± 1% max. + 0,05 Ω
LOAD LIFE	Nominal power Pn 1000 h at 25°C	± 1% max. + 0,05 Ω

POWER RATING CHART

Fig. 2



DETERMINATION OF THE INTERNAL TEMPERATURE RELATED THE USING CONDITIONS :

Chassis mounted resistors :
$$P = \frac{\Delta T}{R_{TH1} + R_{TH2}}$$

Resistors unmounted on chassis :
$$P = \frac{\Delta T}{R_{TH3}}$$

- P = Power dissipation in watt
- ΔT = Temperature difference in °C between the wounded wire and the ambient
- R_{TH1} = Thermal resistance between the wounded wire and the bottom of the box in °C/W
- R_{TH2} = Thermal resistance of the chassis in °C/W (R_{TH3} - R_{TH1})
- R_{TH3} = Thermal resistance between the wounded wire and the ambient in °C/W (R_{TH1} + R_{TH2})

TEMPERATURE RISE

Fig. 3

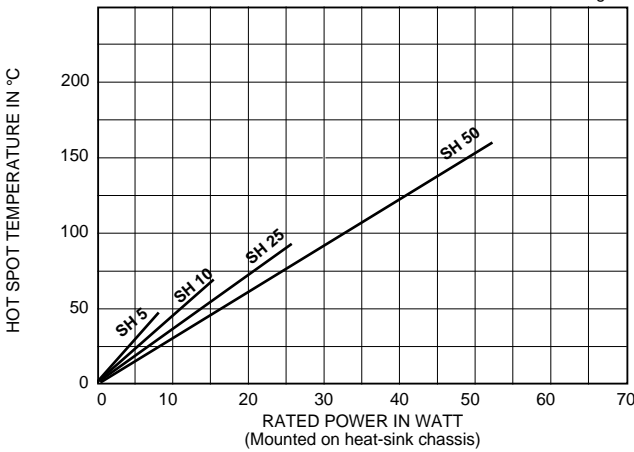


Table 4

	SH5	SH10	SH25	SH50
R _{TH1}	8,5	11	4,5	2
R _{TH3}	47	41	22,5	14

MARKING

SFERNICE trademark, series, style, nominal resistance (in Ω), tolerance (in %), manufacturing date.

ORDERING PROCEDURE

